

VOLTAGE RANGE: 50 - 1000V

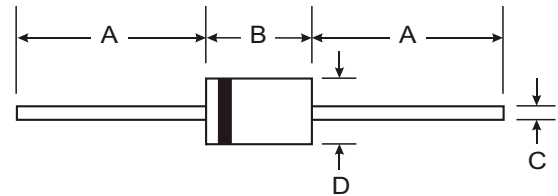
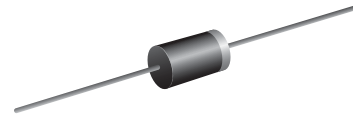
CURRENT: 3.0 A

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



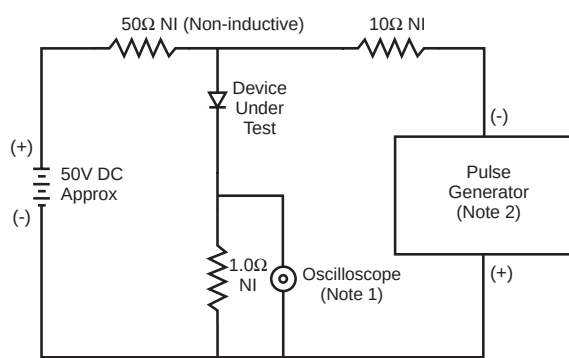
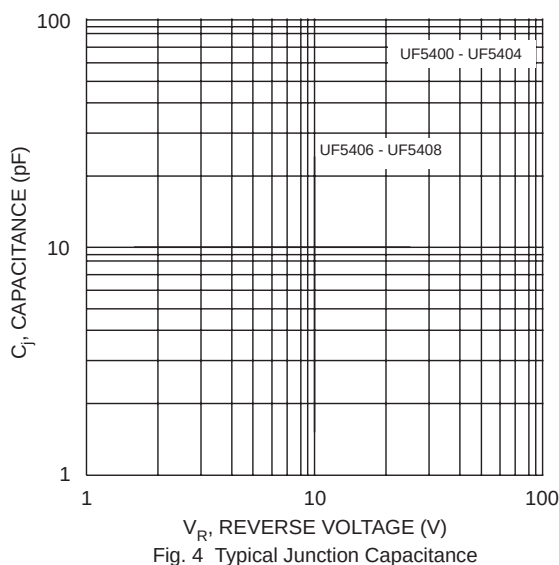
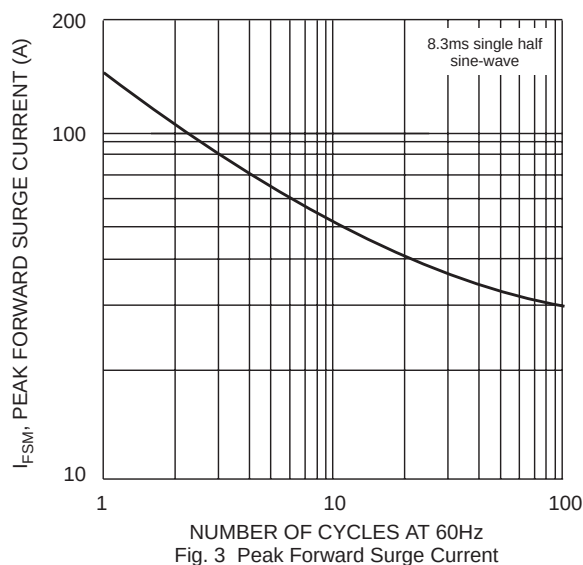
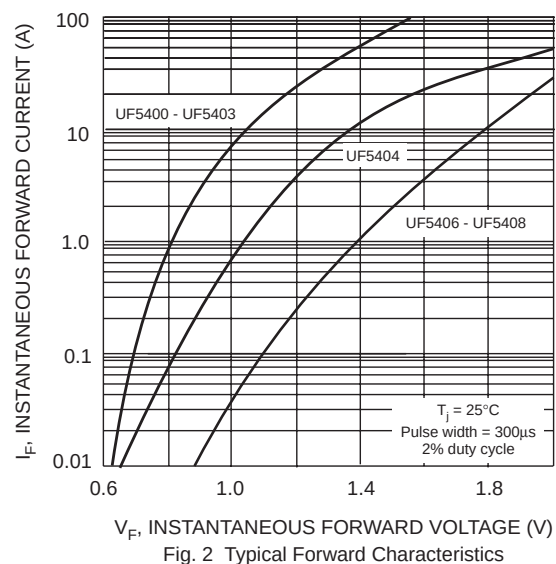
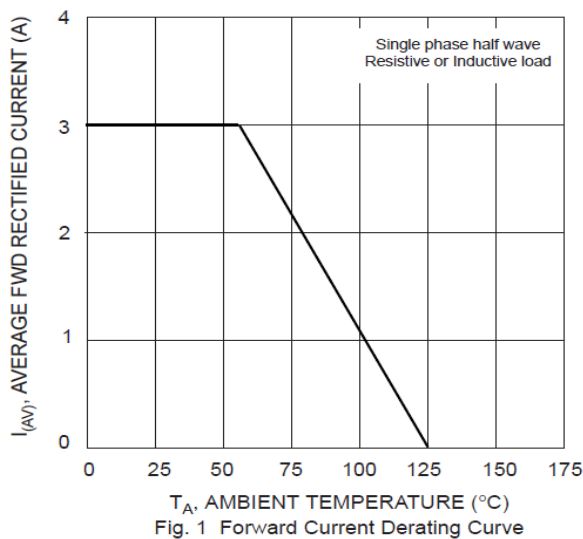
DO-201AD		
Dim	Min	Max
A	25.40	—
B	8.50	9.53
C	0.96	1.06
D	4.80	5.21
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	UF 5400	UF 5401	UF 5402	UF 5403	UF 5404	UF 5406	UF 5407	UF 5408	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	300	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	210	280	420	560	700	V
Average Rectified Output Current (Note 1) @T _A = 55°C	I _O	3.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150								A
Forward Voltage @I _F = 3.0A	V _{FM}	1.0				1.3	1.7			V
Peak Reverse Current At Rated DC Blocking Voltage @T _A = 25°C @T _A = 100°C	I _{RM}	10 100								μA
Reverse Recovery Time (Note 2)	t _{rr}	50					75			nS
Typical Junction Capacitance (Note 3)	C _j	80					50			pF
Operating Temperature Range	T _j	-65 to +125								°C
Storage Temperature Range	T _{STG}	-65 to +150								°C

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case
 2. Measured with $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $IRR = 0.25\text{A}$. See figure 5.
 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.



Notes:

1. Rise Time = 7.0ns max. Input Impedance = 1.0M Ω , 22pF.
2. Rise Time = 10ns max. Input Impedance = 50 Ω .

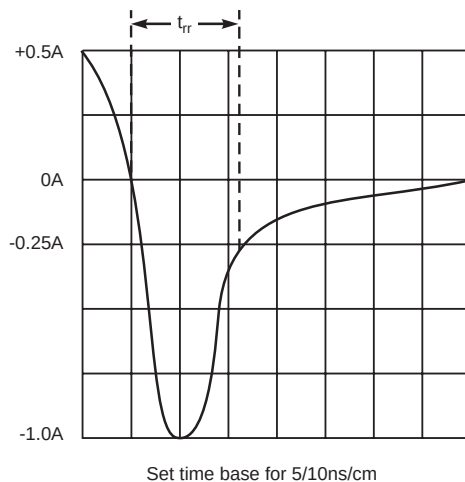


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit